



VERTICAL DEFLECTION BOOSTER

FEATURES

- Power Amplifier
- Flyback Generator
- Thermal Protection
- Output Current up to 2.6 App
- Flyback Voltage up to 90V (on pin 5)
- Suitable for DC Coupling Application

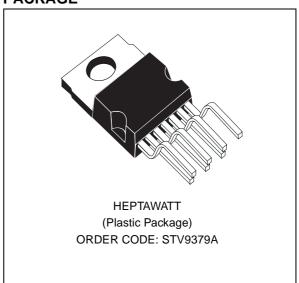
DESCRIPTION

Designed for monitors and high performance TVs, the STV9379A vertical deflection booster delivers flyback voltages close to 90V.

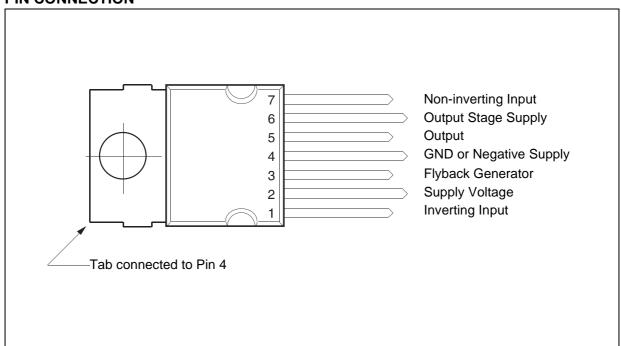
The STV9379A operates with supplies up to 42V and provides up to 2.6 A_{PP} output current to drive the yoke.

The STV9379A is inserted in HEPTAWATT package.

PACKAGE



PIN CONNECTION

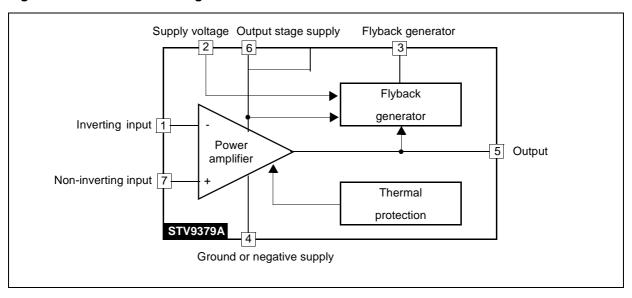


Version 4.2

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BLOCK DIAGRAM

Figure 1. STV9379A block diagram



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|--------------------------------|---|------------------------|------|
| Vs | Supply Voltage (Pin 2) (Note 1) | 50 | V |
| V ₆ | Flyback Peak Voltage (Pin 6) (Note 1) | 100 | V |
| V ₁ ,V ₇ | Amplifier Input Voltage (Pins 1-7) (Note 1) | -0.3, + V _S | V |
| Io | Maximum Output Peak Current (Note 2, Note 3) | 1.8 | Α |
| l ₃ | Maximum Sink Current (first part of flyback) (t < 1ms) | 1.8 | Α |
| l ₃ | Maximum Source Current (t < 1ms) (Note 2) | 1.8 | Α |
| V _{ESD} | ESD Susceptibility: EIAJ Norm (200pF discharged through 0Ω) | 300 | V |
| T _{oper} | Operating Ambient Temperature | -20, +75 | °C |
| T _{stg} | Storage Temperature | -40, +150 | °C |
| Tj | Junction Temperature | + 150 | °C |

Note 1: Versus Pin 4.

Note 2:The output current can reach 5A peak for t $\leq 10 \mu s$ (up to 120Hz)

Note 3: Provided SOAR is respected (see Figures 2 and 3).

THERMAL DATA

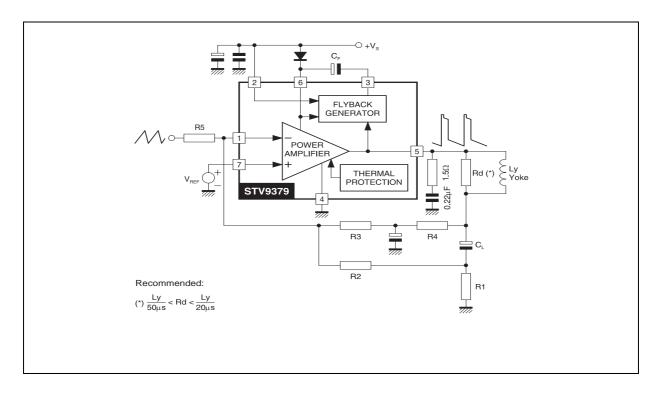
| Symbol | Parameter | Value | Unit |
|-----------------------|---------------------------------------|-------|------|
| R _{th (j-c)} | Junction-Case Thermal Resistance Max. | 3 | °C/W |
| T _t | Temperature for Thermal Shutdown | 150 | °C |
| ΔT_{t} | Hysteresis on Tt | 10 | °C |
| T _{ir} | Recommended Max. Junction Temperature | 120 | °C |

 $\begin{array}{l} \textbf{ELECTRICAL CHARACTERISTICS} \\ \textbf{V}_{\text{S}}\text{=}42 \textbf{V}, \, \textbf{T}_{\text{A}} = 25 ^{\circ} \textbf{C}, \, \text{unless otherwise specified} \end{array}$

| Symbol | Parameter | Test Conditions | Min. | Тур. | Max. | Unit |
|----------------------|---|-------------------------|------|-------|------|-------|
| V _S | Operating Supply Voltage Range | Versus Pin 4 | 10 | | 42 | V |
| l ₂ | Pin 2 Quiescent Current | $I_3 = 0, I_5 = 0$ | | 13 | 20 | mA |
| I ₆ | Pin 6 Quiescent Current | $I_3 = 0, I_5 = 0$ | 5 | 10 | 30 | mA |
| Io | Max. Peak Output Current | | | | 1.3 | Α |
| I ₁ | Amplifier Bias Current | $V_1 = 25V, V_7 = 26V$ | | -0.15 | - 1 | μΑ |
| l ₇ | Amplifier Bias Current | $V_1 = 26V, V_7 = 25V$ | | -0.15 | - 1 | μΑ |
| V _{IO} | Offset Voltage | | | | 7 | mV |
| ΔV _{IO} /dt | Offset Drift Versus Temperature | | | - 10 | | μV/°C |
| GV | Voltage Gain | | 80 | | | dB |
| V_{5L} | Output Saturation Voltage to GND (Pin 4) | I ₅ = 1.3A | | 1 | 1.5 | V |
| V _{5H} | Output Saturation Voltage to Supply (Pin 6) | I ₅ = -1.3A | | 1.6 | 2.1 | V |
| V _{D5-6} | Diode Forward Voltage between Pins 5-6 | I ₅ = 1.3A | | 1.3 | 2 | V |
| V _{D3-2} | Diode Forward Voltage between Pins 3-2 | I ₃ = 1.3A | | 1.3 | 2 | V |
| V _{3L} | Saturation Voltage on Pin 3 | $I_3 = 20 \text{mA}$ | | 0.8 | 1.2 | V |
| V _{3SH} | Saturation Voltage to Pin 2 (2nd part of flyback) | I ₃ = - 1.3A | | 2.9 | 3.6 | V |

APPLICATION CIRCUITS

AC COUPLING



APPLICATION CIRCUITS (CONTINUED)

DC COUPLING.

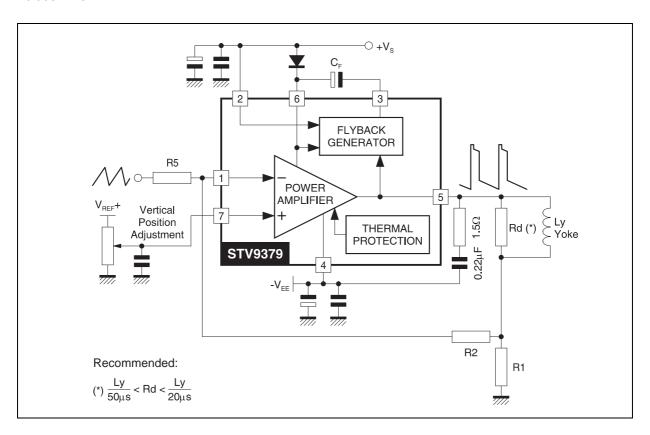


Figure 2. Output transistors SOA (for secondary breakdown)

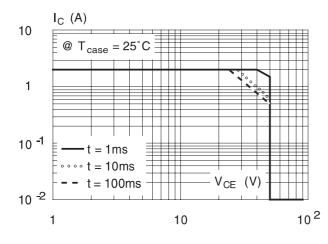
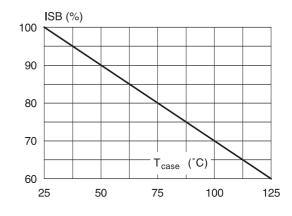
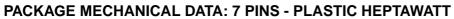
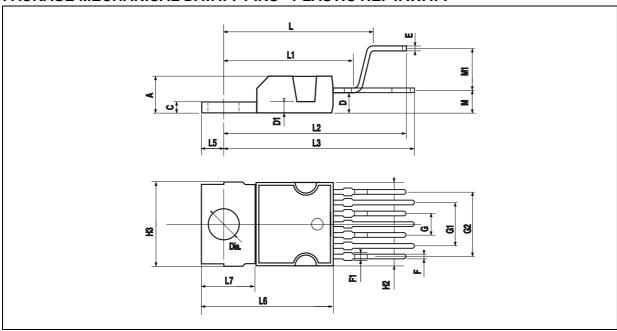


Figure 3. Secondary breakdown
Temperature Derating Curve

(ISB = Secondary Breakdown current)







| Dimensions | Millimeters | | | Inches | | |
|------------|-------------|-------|------|--------|-------|-------|
| | Min. | Тур. | Max. | Min. | Тур. | Max. |
| Α | | | 4.8 | | | 0.189 |
| С | | | 1.37 | | | 0.054 |
| D | 2.4 | | 2.8 | 0.094 | | 0.110 |
| D1 | 1.2 | | 1.35 | 0.047 | | 0.053 |
| E | 0.35 | | 0.55 | 0.014 | | 0.022 |
| F | 0.6 | | 8.0 | 0.024 | | 0.031 |
| F1 | | | 0.9 | | | 0.035 |
| G | 2.41 | 2.54 | 2.67 | 0.095 | 0.100 | 0.105 |
| G1 | 4.91 | 5.08 | 5.21 | 0.193 | 0.200 | 0.205 |
| G2 | 7.49 | 7.62 | 7.8 | 0.295 | 0.300 | 0.307 |
| H2 | | | 10.4 | | | 0.409 |
| H3 | 10.05 | | 10.4 | 0.396 | | 0.409 |
| L | | 16.97 | | | 0.668 | |
| L1 | | 14.92 | | | 0.587 | |
| L2 | | 21.54 | | | 0.848 | |
| L3 | | 22.62 | | | 0.891 | |
| L5 | 2.6 | | 3 | 0.102 | | 0.118 |
| L6 | 15.1 | | 15.8 | 0.594 | | 0.622 |
| L7 | 6 | | 6.6 | 0.236 | | 0.260 |
| M | | 2.8 | | | 0.110 | |
| M1 | | 5.08 | | | 0.200 | |
| Dia. | 3.65 | | 3.85 | 0.144 | | 0.152 |

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